

Changchun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

 $EO-1064-Subnano-Hi/1\sim4000 \mu J/1\sim20 W$ 

## **HIGH ENERGY DIODE** PUMPED ALL-SOLID-STATE **Q-SWITCHED LASER**

High energy diode pumped all solid state Q-switched laser at 1064nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in Lidar, LIBS, Thin film removal, Non-linear Spectroscopy, Specialty marking, and so on.













## SPECIFICATIONS

Wavelength (nm)	1064±1nm	
Operating mode	Q-switched: EO (Electro-optic)	
Single pulse energy (uJ)	2000uJ@5KHz	4000uJ@5KHz
Output power (W)	10	20
Power stability	<2%,<3%,<5%	
Pulse duration (ns)	<1.5ns@5KHz	1.5~2ns@5KHz
Rep. rate (kHz)	100Hz~10kHz (Customizable)	
Beam diameter (mm)	~2mm	~2.5mm
Beam divergence, full angle (mrad)	<3mrad	
Cooled method	Air cooled	
Warm-up time (minutes)	<15	
Power supply	DC 24V	
Operating temperature (°C)	15~30	
Expected lifetime (hours)	10000h	
Warranty period	l year	

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